

# 400mA Low-dropout Linear Voltage Regulator with Voltage Detector Function

## FEATURES

Including MOSFET for V<sub>OUT1</sub>, LDO for V<sub>OUT2</sub>, voltage detector and shutdown control  
Low dropout voltage of 550mV (typ.) at 400mA output current (V<sub>OUT2</sub>)  
Guaranteed 700mA output current for V<sub>OUT1</sub> and 400mA for V<sub>OUT2</sub>  
Low ground current of 120µA  
Output voltage accuracy of 2% for V<sub>OUT2</sub>  
Current limit function  
Built-in voltage detector  
Shutdown control for V<sub>OUT1</sub> and V<sub>OUT2</sub>

## APPLICATIONS

Voltage Regulator for DVD-ROM and CD-ROM Drives  
Voltage Regulator for HDD and Floppy Drives  
Voltage Regulator for circuits with Stepping Motors or Servo Motors

## DESCRIPTION

The SS6729 is a low dropout linear regulator with voltage detection function.

It can be divided into four main functional blocks, including a MOSFET for V<sub>OUT1</sub>, an LDO for V<sub>OUT2</sub>, a voltage detector and two shutdown controls.

The voltage detector can be used to detect V<sub>CC</sub>. The detecting voltage of the voltage detector is from 3.0V to 4.6V in 0.1V steps, and the output (D<sub>OUT</sub>) of the V<sub>CC</sub> voltage detection has an adjustable delay time before indicating V<sub>CC</sub>. The user only needs to add one external capacitor to implement it. When V<sub>CC</sub> is below the set detection voltage, D<sub>OUT</sub> is at logic-low.

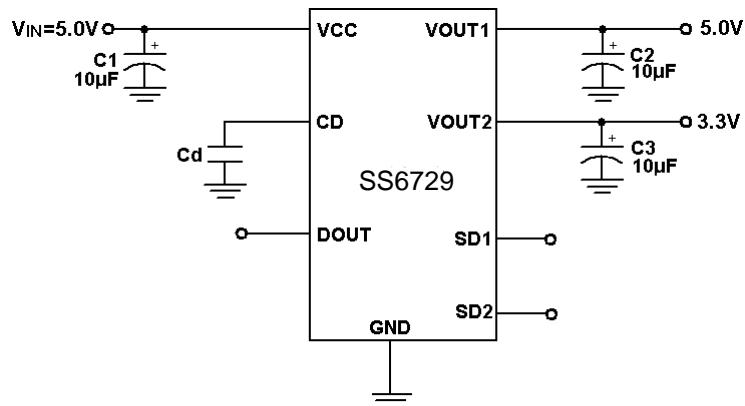
V<sub>OUT1</sub> is controlled by the SD1 pin. When SD1 is logic-high, the internal MOSFET for V<sub>OUT1</sub> is switched off, and vice versa.

The LDO output voltage (V<sub>OUT2</sub>) is from 1.8V to 4.0V with 0.1V step for different application. It is also controlled by SD2 pin. When SD2 is logic high, the internal LDO for V<sub>OUT2</sub> will be shutdown, vice versa.

The superior characteristics of the SS-6729 include very low dropout voltage, and 2% accuracy output voltage. Typical ground current remains 120µA, from no load to maximum loading conditions. Dropout voltage of V<sub>OUT2</sub> is 550mV at 400mA output current. Output current limiting is provided at V<sub>OUT1</sub> and V<sub>OUT2</sub>.

SS6729 comes in the popular SO8 package.

## TYPICAL APPLICATION CIRCUIT



Power Source for CD-drivers and DVD-drivers

## ORDERING INFORMATION

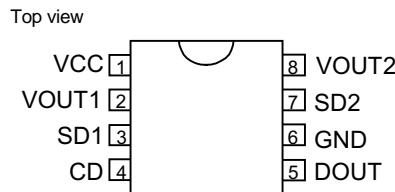
SS6729XXXX-CXXX

|  |  |
|--|--|
| Packing type   |  |
| TB: tubes (PDIP is only available in tubes)                              |  |
| TR: tape and reel  |  |
| Package type   |  |
| N: plastic DIP   |  |
| S: small outline   |  |
| LDO output voltage   |  |
| 18: 1.8V   |  |
| :  |  |
| :  |  |
| 40: 4.0V   |  |
| Voltage detector voltage   |  |
| 30: 3.0V   |  |
| :  |  |
| :  |  |
| 46: 4.6V   |  |
| LDO output voltage and voltage detector are available on 0.1V increments |  |

Example: SS6729-3018CSTR

→ 3.0V voltage detector, 1.8V LDO output  
voltage, in SO-8, shipped on tape and reel

## PIN CONFIGURATION



## ABSOLUTE MAXIMUM RATINGS

|  |             |
|--|-------------|
| Input Supply Voltage .....                         | -0.3~8V     |
| Operating Ambient Temperature Range .....          | -40°C~ 85°C |
| Storage Temperature Range .....                    | -65°C~150°C |
| Thermal Resistance $\theta_{JA}$                   |             |
| SOIC Package .....                                 | 100°C/W     |
| SOIC Package (with 3 square inches of Copper)..... | 90°C/W      |

## ELECTRICAL CHARACTERISTICS

( $T_A = 25^\circ C$ ,  $V_{IN} = 5.0V$ ,  $I_{OUT1} = I_{OUT2} = 400mA$ ,  
 $SD1 = SD2 = \text{low}$ , unless otherwise specified)

| PARAMETER  | TEST CONDITIONS   | MIN.                  | TYP.      | MAX.                  | UNIT            |
|--|---|-----------------------|-----------|-----------------------|-----------------|
| Ground Current   | $I_{OUT1}=0.1mA\sim700mA$<br>$I_{OUT2}=0.1mA\sim400mA$<br>$V_{IN}=4.0V\sim8.0V$ |                       | 120       | 200                   | $\mu A$         |
| Output Voltage Temperature Coefficiency                | (Note 1)  |                       | 100       |                       | PPM/ $^\circ C$ |
| <b>V<sub>OUT1</sub></b>                                |   |                       |           |                       |                 |
| Output MOSFET Resistance                               | $V_{IN}=5.0V$   | 370                   | 450       |                       | $m\Omega$       |
| Current Limit(Note 3)                                  |   | 700                   | 950       |                       | $mA$            |
| Output Turn-on Rise Delay                              |   | 100                   |           |                       | $\mu s$         |
| Output Turn-on Rise Time                               |   | 1000                  |           |                       | $\mu s$         |
| SD1 Pin Voltage  | $V_{SD}=\text{Logic}'0"$  |                       | 0.8       |                       | $V$             |
|  | $V_{SD}=\text{Logic}'1"$  | 2.4                   |           |                       |                 |
| <b>V<sub>OUT2</sub> ( 1.8V ~ 4.0V with 0.1V step )</b> |   |                       |           |                       |                 |
| LDO Output Voltage                                     | No Load   | $V_{SET} \times 0.98$ | $V_{SET}$ | $V_{SET} \times 1.02$ | $V$             |
| Line Regulation  | $I_L=1mA, V_{IN}=4.0V\sim8.0V$  | 3                     | 10        |                       | $mV$            |
| Load Regulation<br>(Note 2)                            | $V_{IN}=5V, I_L=0.1mA\sim400mA$   | 50                    | 90        |                       | $mV$            |
| Current Limit<br>(Note 3)                              |   | 400                   | 650       |                       | $mA$            |

**ELECTRICAL CHARACTERISTICS (cont'd.)**

| PARAMETER  | TEST CONDITIONS                | MIN.                   | TYP.                  | MAX.                   | UNIT |
|--|--------------------------------|------------------------|-----------------------|------------------------|------|
| Dropout Voltage<br>(Note 4)                            | $V_{OUT} \geq 3.3V$            | $I_L=100mA$            | 140                   | 200                    | mV   |
|  |                                | $I_L=200mA$            | 280                   | 350                    |      |
|  |                                | $I_L=300mA$            | 420                   | 500                    |      |
|  |                                | $I_L=400mA$            | 550                   | 700                    |      |
|  | $2.5V \leq V_{OUT} < 3.3V$     | $I_L=100mA$            | 250                   | 300                    |      |
|  |                                | $I_L=200mA$            | 420                   | 500                    |      |
|  |                                | $I_L=300mA$            | 600                   | 700                    |      |
|  |                                | $I_L=400mA$            | 780                   | 900                    |      |
|  | $V_{OUT} < 2.5V$               | $I_L=100mA$            | 700                   | 800                    |      |
|  |                                | $I_L=200mA$            | 880                   | 950                    |      |
|  |                                | $I_L=300mA$            | 1050                  | 1150                   |      |
|  |                                | $I_L=400mA$            | 1220                  | 1400                   |      |
| SD2 Pin Voltage  | $V_{SD}=\text{Logic"0"}$       |                        |                       | 0.8                    | V    |
|  | $V_{SD}=\text{Logic"1"}$       |                        |                       | 2.4                    |      |
| <b>Voltage Detector ( 3.0V ~ 4.6V with 0.1V step )</b> |                                |                        |                       |                        |      |
| Detect Voltage( $V_{DET}$ )                            |                                | $V_{DSET} \times 0.98$ | $V_{DSET}$            | $V_{DSET} \times 1.02$ | V    |
| Detect Threshold Hysteresis                            |                                |                        | $V_{DET} \times 1.05$ |                        | V    |
| $V_{DOUT}$   | When $V_{DET}$ is Detected     |                        |                       | 0.6                    | V    |
|  | When $V_{DET}$ is not Detected |                        |                       | 1.65                   |      |
| Delay Time   | CD Pin Open                    |                        | 1                     | 3                      | ms   |

Note 1: Guaranteed by design.

Note 2: Regulation is measured at constant junction temperature, using pulse testing with a low ON time.

Note 3: Current limit is measured by pulsing a short time.

Note 4: Dropout voltage is defined as the input to output differential at which the output voltage drops 100mV below the value measured with a 1V differential.

## TYPICAL PERFORMANCE CHARACTERISTICS

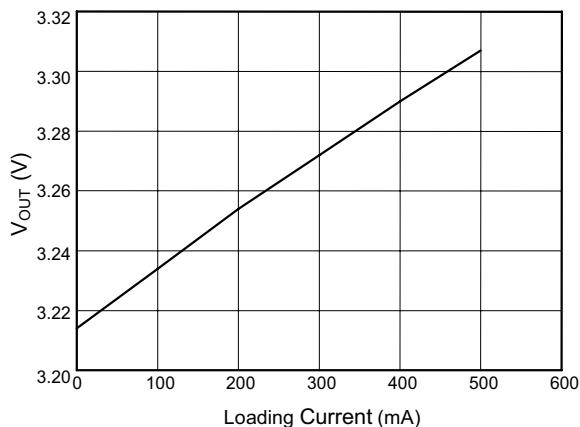


Fig. 1 Output voltage vs. Loading Current

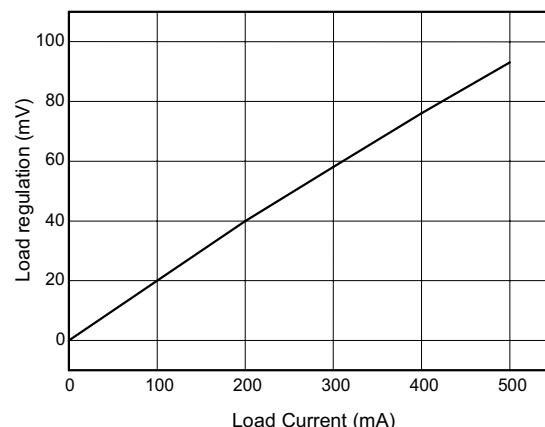


Fig. 2 Load Regulation

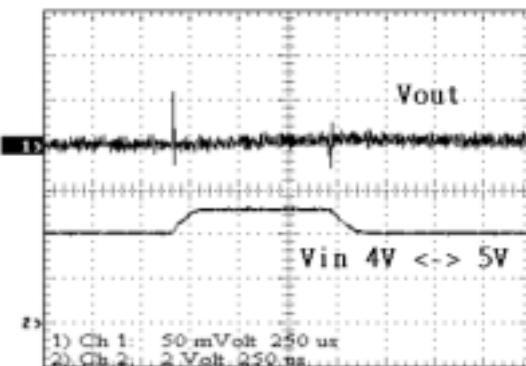


Fig. 3 Line Transient

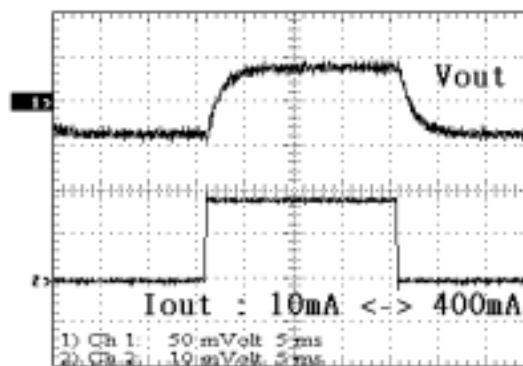


Fig. 4 Load Transient

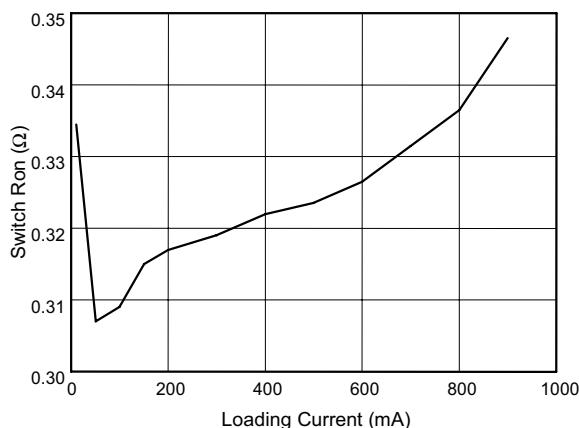


Fig. 5 Switch  $R_{on}$  vs. Loading current (mA)

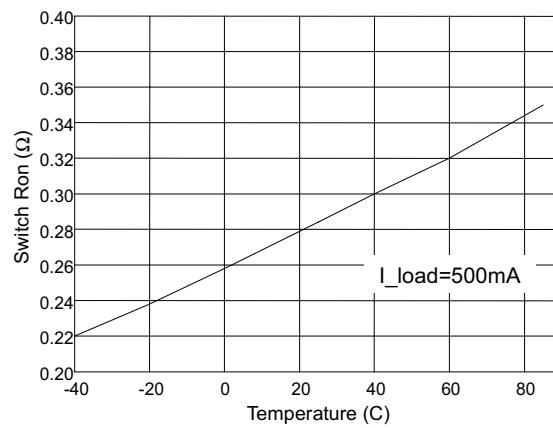


Fig. 6 Switch  $R_{on}$  vs. Temperature

## TYPICAL PERFORMANCE CHARACTERISTICS (cont'd.)

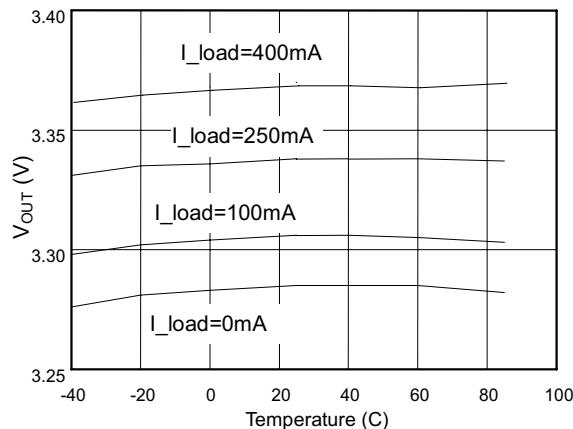


Fig. 7 Output voltage vs. Temperature

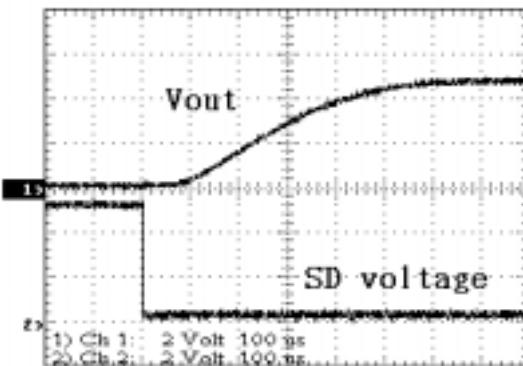


Fig. 8 Output Turn-on Rise Time

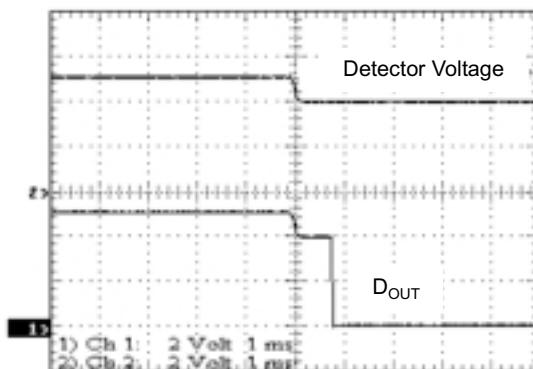


Fig. 9 Built-in Delay Time Waveform

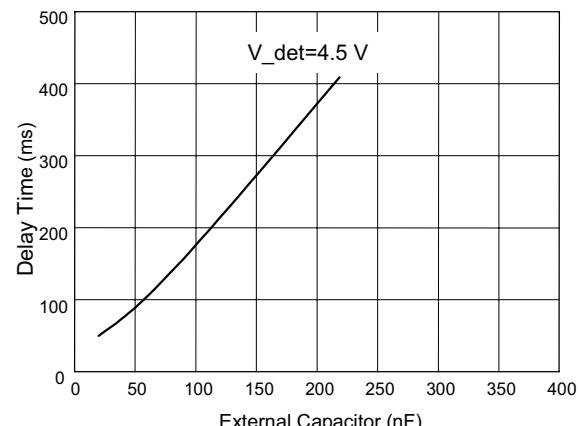
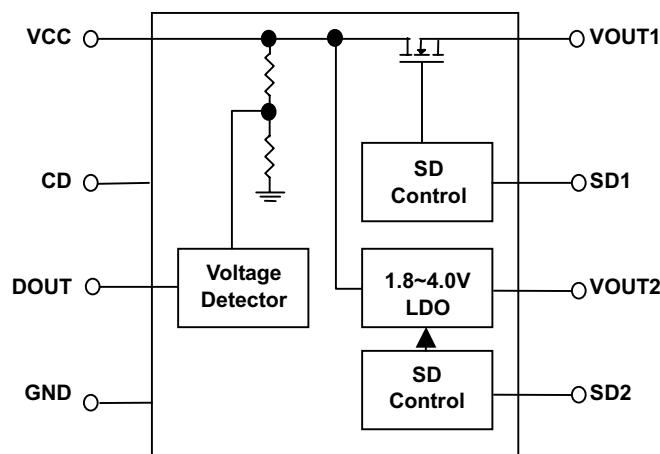


Fig. 10 Delay Time vs. External Capacitor

## BLOCK DIAGRAM

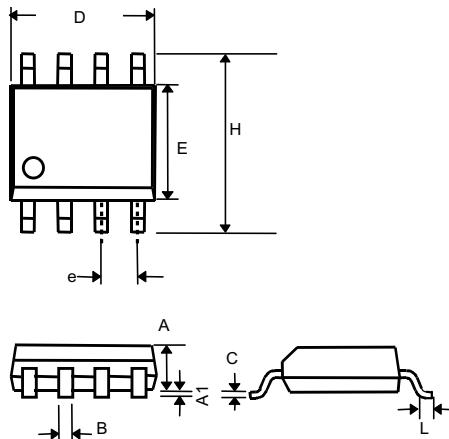


## PIN DESCRIPTION

- |               |   |               |   |
|---------------|---|---------------|---|
| PIN 1: VCC-   | This pin is the main input supply for the IC, normally 5V   | PIN 4: CD-    | This pin is to determine delay time by attaching a capacitor                  |
| PIN 2: VOUT1- | This pin is the voltage output which is connected to Vcc directly via internal MOSFET switch, normally 5V | PIN 5: DOUT-  | This pin is voltage detector output, pulled low when V <sub>IN</sub> detected |
| PIN 3: SD1-   | VOUT1 shutdown pin. Logic high input for disabling the internal MOS Switch.                               | PIN 6: GND-   | IC ground pin   |
|               |   | PIN 7: SD2-   | VOUT2 shutdown pin. Logic high input for disabling LDO output.                |
|               |   | PIN 8: VOUT2- | This pin is 3.3V LDO voltage output   |

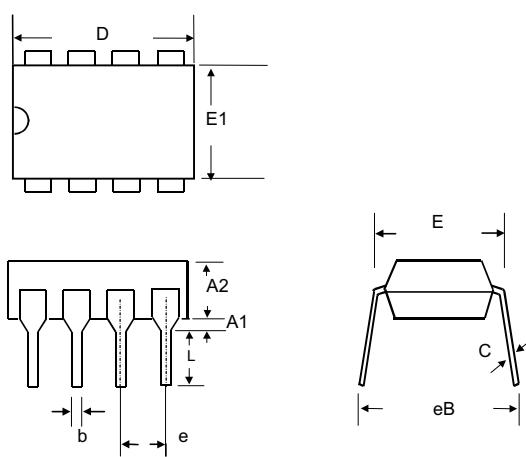
## PHYSICAL DIMENSIONS

8-lead plastic SO (units: mm)



| SYMBOL | MIN       | MAX  |
|--------|-----------|------|
| A      | 1.35      | 1.75 |
| A1     | 0.10      | 0.25 |
| B      | 0.33      | 0.51 |
| C      | 0.19      | 0.25 |
| D      | 4.80      | 5.00 |
| E      | 3.80      | 4.00 |
| e      | 1.27(TYP) |      |
| H      | 5.80      | 6.20 |
| L      | 0.40      | 1.27 |

8 lead plastic DIP (units: mm)



| SYMBOL | MIN        | MAX   |
|--------|------------|-------|
| A1     | 0.381      | —     |
| A2     | 2.92       | 4.96  |
| b      | 0.35       | 0.56  |
| C      | 0.20       | 0.36  |
| D      | 9.01       | 10.16 |
| E      | 7.62       | 8.26  |
| E1     | 6.09       | 7.12  |
| e      | 2.54 (TYP) |       |
| eB     | —          | 10.92 |
| L      | 2.92       | 3.81  |

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